# Low Noise, High IP3 **Monolithic Amplifier**

## **PSA-5454+**

0.05 to 4 GHz 50Ω



### **The Big Deal**

- Ultra Low Noise Figure, 0.8 dB
- High IP3/Low Current, 20mA at +5V
- Wideband, up to 4 GHz

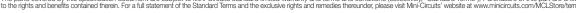
### **Product Overview**

Mini-Circuits PSA-5454+ is a E-PHEMT based Ultra-Low Noise MMIC Amplifier operating from 50 MHz to 4 GHz with a unique combination of low noise and high IP3 making this amplifier ideal for sensitive receiver applications. This design operates on a single 5V supply at only 20mA and is internally matched to 50 ohms.

| Feature                 | Advantages   |  |  |
|-------------------------|--|--|--|
| Ultra Low Noise, 0.8 dB | Outstanding Noise Figure, measured in a 50 Ohm environment without any external matching   |  |  |
| High IP3, 25 dBm        | Combining Low Noise and High IP3 makes this MMIC amplifier ideal for Low Noise<br>Receiver Front End (RFE) because it gives the user advantages at both ends of the dynamic<br>range: sensitivity & two-tone spur-free dynamic range |  |  |
| Low Current, 20 mA      | At only 20mA, the PSA-5454+ is ideal for remote applications with limited available power or densely packed applications where thermal management is critical.   |  |  |
| Broad Band              | Operating over a broadband the PSA-5454+ covers the primary wireless communications bands:<br>Cellular, PCS, LTE, WiMAX  |  |  |
| Internally Matched      | No external matching elements required to achieve the advertised noise and output power over t full band   |  |  |
| SOT-363 Package         | Small size, industry standard package  |  |  |
| Max Input Power, +15dBm | Ruggedized design operates up to input powers of +15dBm without the need of an external limiter  |  |  |
| High Reliability        | Low, small signal operating current of 30 mA nominal maintains junction temperatures typically below 105°C at 85°C ground lead temperature   |  |  |

## **Key Features**

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# Low Noise, High IP3 **Monolithic Amplifier**

#### 0.05 to 4 GHz **50**Ω

#### **Product Features**

- Single Positive Supply Voltage, +5V, Id=20mA
- Ultra Low Noise Figure, 0.8 dB typ. at 1GHz
- High IP3, 25 dBm typ. 1GHz
- · Gain, 18dB typ. at 1GHz
- Output Power, up to +14 dBm typ.
- Micro-miniature size SOT-363 package
- Aqueous washable

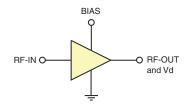
#### **Typical Applications**

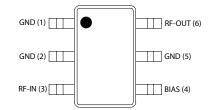
- Cellular
- ISM
- GSM
- WCDMA
- LTE
- WiMAX
- WLAN
- UNII and HIPERLAN

#### **General Description**

PSA-5454+ is an advanced wide band, high dynamic range, low noise, high IP3, high output power, monolithic amplifier. Manufactured using E-PHEMT\* technology enables it to work with a single positive supply voltage.

#### simplified schematic and pin description





| Function    | Pin<br>Number  | <b>Description</b> (See Application Circuit, Fig. 3)                 |  |
|-------------|--|--|--|
| RF IN       | 3  | RF input pin (connect to RF-IN via blocking cap C1 and Pin 4 via L2) |  |
| RF-OUT & Vd | RF-OUT & Vd      6      RF output pin (connected to RF-out via blocking cap C2 and supply voltage V via RF Choke L1) |  |  |
| BIAS        | 4  | Connected to Vs via Rbias. (Connect to ground via C4 & R1)           |  |
| GND         | 1,2,5  | Connections to ground  |  |

\* Enhancement mode pseudomorphic High Electron Mobility Transistor.

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**PSA-5454+** 

Generic photo used for illustration purposes only CASE STYLE: CA1389

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

#### Monolithic Low Noise E-PHEMT MMIC Amplifier

# **PSA-5454+**

| Parameter                                   | Condition (GHz) | Min. | Тур.  | Max. | Units |  |
|---|-----------------|------|-------|------|-------|--|
| Frequency Range                             |                 | 0.05 |       | 4.0  | GHz   |  |
| DC Voltage (V <sub>d</sub> )                |                 |      | 5.0   |      | V     |  |
| DC Current (I <sub>d</sub> ) <sup>(6)</sup> |                 | 12   | 20    | 40   | mA    |  |
| DC Current (I <sub>Rbias</sub> )            |                 |      | 0.6   |      | mA    |  |
|   | 0.05            |      | 2.6   | _    | dB    |  |
|   | 0.5             |      | 0.8   | _    |       |  |
| Noise Figure                                | 1.0             |      | 0.8   |      |       |  |
| Noise Figure                                | 2.0             |      | 1.1   | 1.3  |       |  |
|   | 3.0             |      | 1.4   | _    |       |  |
|   | 4.0             |      | 1.7   | —    |       |  |
|   | 0.05            | _    | 21.1  | _    | dB    |  |
|   | 0.5             | _    | 21.6  | l —  |       |  |
| Gain  | 1.0             | _    | 18.3  | _    |       |  |
| Gain  | 2.0             | 12.2 | 13.6  | 14.9 |       |  |
|   | 3.0             | _    | 10.9  | l —  |       |  |
|   | 4.0             |      | 9.3   |      |       |  |
| Input Return Loss                           | 0.05-0.5        |      | 8.0   |      | dB    |  |
| Input Neturi Loss                           | 0.5-4.0         |      | 6.0   |      | uв    |  |
|   | 0.05-0.5        |      | 7.0   |      | dB    |  |
| Output Return Loss                          | 0.5-4.0         |      | 15.0  |      |       |  |
|   | 0.05            |      | 21.2  |      | dBm   |  |
|   | 0.5             |      | 24.7  |      |       |  |
| 0.1.170                                     | 1.0             |      | 25.3  |      |       |  |
| Output IP3                                  | 2.0             |      | 26.3  |      |       |  |
|   | 3.0             |      | 26.2  |      |       |  |
|   | 4.0             |      | 26.0  |      |       |  |
|   | 0.05            |      | 6.6   |      | dBm   |  |
|   | 0.5             |      | 14.6  |      |       |  |
| Output Power @ 1 dB compression (P1dB) (2)  | 1.0             |      | 15.0  |      |       |  |
| Output Fower @ 1 db compression (F1dB)      | 2.0             |      | 14.0  |      |       |  |
|   | 3.0             |      | 14.0  |      |       |  |
|   | 4.0             |      | 14.5  |      |       |  |
| DC Current Variation vs. Temperature (3)    |                 |      | -0.08 |      | mA/°C |  |
| Thermal Resistance                          |                 |      | 165   |      | °C/W  |  |

#### Electrical Specifications<sup>(1)</sup> at 25°C, Zo=50Ω, (refer to characterization circuit, Fig. 1)

#### Absolute Maximum Ratings<sup>(4)</sup>

| Parameter                 | Ratings        |  |  |
|---------------------------|----------------|--|--|
| Operating Temperature (5) | -40°C to 85°C  |  |  |
| Storage Temperature       | -65°C to 150°C |  |  |
| Channel Temperature       | 150°C          |  |  |
| DC Voltage (Pin 6)        | 6V             |  |  |
| Power Dissipation         | 390mW          |  |  |
| DC Current (Pin 6)        | 60mA           |  |  |
| Bias Current (Pin 4)      | 10mA           |  |  |
| Input Power (CW) (7)      | 15dBm          |  |  |

- (1) Measured on Mini-Circuits Characterization test board TB-533+
- See Characterization Test Circuit (Fig. 1)
- (2) Specified with external current limiting of 30 mA. Capable of higher P1dB at higher currents (see Fig. 2)
   <sup>(3)</sup> Current at 85°C - Current at -45°C)/130
- <sup>(4)</sup> Permanent damage may occur if any of these limits are exceeded.
- <sup>(5)</sup> Defined with reference to ground pad temperature.
  <sup>(6)</sup> Specified DC current consumption is under small signal conditions.
- Current will increase with input RF Power. To maintain maximum current consumption, external DC current limiting circuits are required on Vd line.
- <sup>(7)</sup> Maximum input power is specified based upon external Vd current limiting of 40 mA. Maximum input power will degrade without external current limiting.

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#### **Characterization Test Circuit**

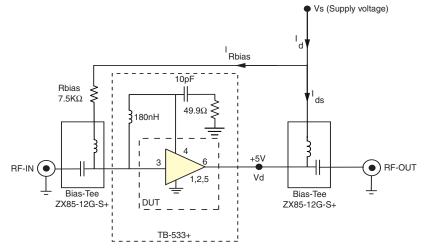


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-533+) Gain, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

- 1. Gain: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
- 3. Vs adjusted for 5V at device (Vd), compensating loss of bias tee.

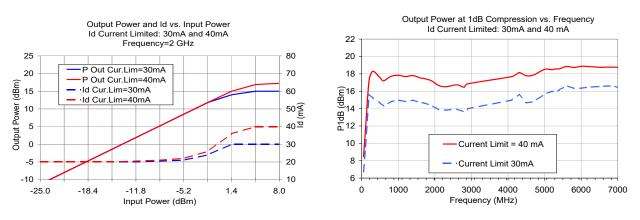


Fig 2. Output Power and Id vs. Input Power and Frequency.

Performance measured on Mini-Circuits Characterization test board TB-533+. See Characterization Test Circuit (Fig. 1) Measurements performed with current (Id) limited as noted.

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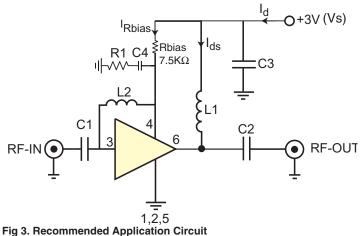
#### Mini-Circuits



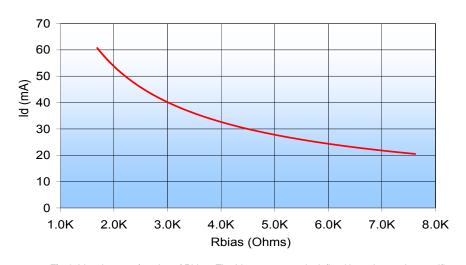
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#### **Recommended Application Circuit**

(refer to evaluation board for PCB Layout and component values)



Note: Resistance of L1, 0.1-0.2Ω typically



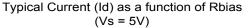


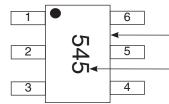
Fig 4. Id varies as a function of Rbias. The Id current range is defined based upon the specific Rbias value noted in the Application Circuit (Fig 3). Rbias may be adjusted to optimize Id for a customers' application. RF performance will vary accordingly.

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#### **Product Marking**



black body laser or white ink marking model family designation

Marking may contain other features or characters for internal lot control

#### Additional Detailed Technical Information

Additional information is available on our web site www.minicircuits.com. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: CA1389 Plastic molded SOT-363 package, lead finish: matte tin

Tape & Reel: F101 Standard quantities availabe on reel: 7" reels with 20, 50, 100, 200, 500, 1K, or 2K devices.

Suggested Layout for PCB Design: PL-311

Evaluation Board: TB-534-4+

Environmental Ratings: ENV08T2

#### ESD Rating

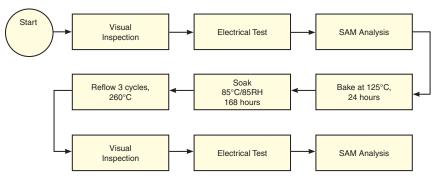
Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (<100V) in accordance with ANSI/ESD STM5.2-1999; passes 40V

#### MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

#### **MSL Test Flow Chart**



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